

Edition 1.0 2021-09

INTERNATIONAL **STANDARD**

colour

Semiconductor devices – Micro-electromechanical devices – Part 40: Test methods of micro-electromechanical inertial shock threshold

Jone Click to view the



THIS PUBLICATION IS COPYRIGHT PROTECTED Copyright © 2021 IEC, Geneva, Switzerland

All rights reserved. Unless otherwise specified, no part of this publication may be reproduced or utilized in any form or by any means, electronic or mechanical, including photocopying and microfilm, without permission in writing from either IEC or IEC's member National Committee in the country of the requester. If you have any questions about IEC copyright or have an enquiry about obtaining additional rights to this publication, please contact the address below or your local IEC member National Committee for further information.

Tel.: +41 22 919 02 11

IEC Central Office 3, rue de Varembé CH-1211 Geneva 20 Switzerland

info@iec.ch www.iec.ch

About the IEC

The International Electrotechnical Commission (IEC) is the leading global organization that prepares and publishes International Standards for all electrical, electronic and related technologies.

The technical content of IEC publications is kept under constant review by the IEC. Please make sure that you have the latest edition, a corrigendum or an amendment might have been published.

IEC publications search - webstore.iec.ch/advsearchform

The advanced search enables to find IEC publications by a variety of criteria (reference number, text, technical committee, ...). It also gives information on projects, replaced and withdrawn publications.

IEC Just Published - webstore.iec.ch/justpublishedStay up to date on all new IEC publications. Just Published details all new publications released. Available online and once a month by email.

IEC Customer Service Centre - webstore.iec.ch/csc

If you wish to give us your feedback on this publication or ECNORM. Click to view need further assistance, please contact the Customer Service. Centre: sales@iec.ch.

IEC online collection - oc.iecch

Discover our powerful search engine and read freely all the publications previews. With a subscription you will always have access to up to date content tailored to your needs.

Electropedia - www.electropedia.org

The world's leading online dictionary on electrotechnology, containing more than 22 000 terminological entries in English and French, with equivalent terms in 18 additional languages. Also known as the International Electrotechnical Vocabulary (IEV) online.



Edition 1.0 2021-09

INTERNATIONAL **STANDARD**

Semiconductor devices – Micro-electromechanical devices – Part 40: Test methods of micro-electromechanical inertial shock threshold colour

ome ome click to view the

INTERNATIONAL ELECTROTECHNICAL COMMISSION

ICS 31.080.99 ISBN 978-2-8322-1018-7

Warning! Make sure that you obtained this publication from an authorized distributor.

CONTENTS

FOREWORD		3		
1 Scope		5		
2 Normative references		5		
3 Terms and definitions	·			
4 Essential ratings and	characteristics	7		
4.1 Recommended	operating condition	7		
	-	7		
		7		
5.1 Switch type		7. AO: DO 7. AO:		
5.2 Static threshold		<u>0</u> 0		
5.2.1 Test metho	d 1			
5.2.2 Test metho	d 2	8		
5.3 Dynamic thresh	old	10		
5.3.1 Test system	n	10		
5.3.2 Test proced	dure	11		
Figure 2 – Test system 1 c Figure 3 – Test system 2 c Figure 4 – Circuit diagram Figure 5 – Static threshold Figure 6 – Test system of	of static threshold	icaDinertia shock switch		
Table 1 – Characteristics of the switch threshold				
	()	11		
Table 5 – Test parameters	A gynamio unosnota			

INTERNATIONAL ELECTROTECHNICAL COMMISSION

SEMICONDUCTOR DEVICES – MICRO-ELECTROMECHANICAL DEVICES –

Part 40: Test methods of micro-electromechanical inertial shock switch threshold

FOREWORD

- 1) The International Electrotechnical Commission (IEC) is a worldwide organization for standardization comprising all national electrotechnical committees (IEC National Committees). The object of IEC is to promote international co-operation on all questions concerning standardization in the electrical and electronic fields. To this end and in addition to other activities, IEC publishes International Standards, Technical Specifications, Technical Reports, Publicly Available Specifications (PAS) and Guides (hereafter referred to as "IEC Publication(s)"). Their preparation is entrusted to technical committees; any IEC National Committee interested in the subject dealt with may participate in this preparatory work. International, governmental and non-governmental organizations liaising with the IEC also participate in this preparation. IEC collaborates closely with the International Organization for Standardization (ISO) in accordance with conditions determined by agreement between the two organizations.
- 2) The formal decisions or agreements of IEC on technical matters express as nearly as possible, an international consensus of opinion on the relevant subjects since each technical committee has representation from all interested IEC National Committees.
- 3) IEC Publications have the form of recommendations for international use and are accepted by IEC National Committees in that sense. While all reasonable efforts are made to ensure that the technical content of IEC Publications is accurate, IEC cannot be held responsible for the way in which they are used or for any misinterpretation by any end user.
- 4) In order to promote international uniformity, IEC National Committees undertake to apply IEC Publications transparently to the maximum extent possible in their national and regional publications. Any divergence between any IEC Publication and the corresponding national or regional publication shall be clearly indicated in the latter.
- 5) IEC itself does not provide any attestation of conformity. Independent certification bodies provide conformity assessment services and, in some areas, access to IEC marks of conformity. IEC is not responsible for any services carried out by independent certification bodies.
- 6) All users should ensure that they have the latest edition of this publication.
- 7) No liability shall attach to IEC or its directors, employees, servants or agents including individual experts and members of its technical committees and IEC National Committees for any personal injury, property damage or other damage of any nature whatsoever, whether direct or indirect, or for costs (including legal fees) and expenses arising out of the publication, use of, or reliance upon, this IEC Publication or any other IEC Publications.
- 8) Attention is drawn to the Normative references cited in this publication. Use of the referenced publications is indispensable for the correct application of this publication.
- 9) Attention is drawn to the possibility that some of the elements of this IEC Publication may be the subject of patent rights. IEC shall not be held responsible for identifying any or all such patent rights.

IEC 62037-40 has been prepared by subcommittee 47F: Micro-electromechanical systems, of IEC technical committee 47: Semiconductor devices. It is an International Standard.

The text of this International Standard is based on the following documents:

DRAFT	Report on voting	
47F/384/FDIS	47F/388/RVD	

Full information on the voting for its approval can be found in the report on voting indicated in the above table.

The language used for the development of this International Standard is English.

This document was drafted in accordance with ISO/IEC Directives, Part 2, and developed in accordance with ISO/IEC Directives, Part 1 and ISO/IEC Directives, IEC Supplement, available at www.iec.ch/members_experts/refdocs. The main document types developed by IEC are described in greater detail at www.iec.ch/standardsdev/publications.

A list of all parts in the IEC 62047 series, published under the general title *Semiconductor devices – Micro-electromechanical devices*, can be found on the IEC website.

The committee has decided that the contents of this document will remain unchanged until the stability date indicated on the IEC website under webstore.iec.ch in the data related to the specific document. At this date, the document will be

- reconfirmed,
- withdrawn,
- replaced by a revised edition, or
- amended.

IMPORTANT – The "colour inside" logo on the cover page of this document indicates that it contains colours which are considered to the useful for the correct understanding of its contents. Users should therefore print this document using a colour printer.

SEMICONDUCTOR DEVICES -MICRO-ELECTROMECHANICAL DEVICES -

Part 40: Test methods of micro-electromechanical inertial shock switch threshold

Scope

This part of IEC 62047 specifies the test conditions and methods of micro-electromechanical inertial shock switch threshold. This document applies to normally open micro-OF IEC 620AT AO! electromechanical inertial shock switch.

2 Normative references

There are no normative references in this document.

Terms and definitions

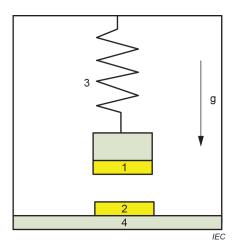
For the purposes of this document, the following terms and definitions apply.

ISO and IEC maintain terminological databases for use in standardization at the following addresses:

- IEC Electropedia: available at http://www.electropedia.org/
- ISO Online browsing platform: available at http://www.iso.org/obp

micro-electromechanical shock inertial switch

device that is fabricated by micro-electromechanical system technology, and is closed or open via the contact or separation of fixed and movable electrode under or above a certain acceleration, also as known threshold switch, acceleration switch, or g switch



Key

- 1 movable electrode
- 2 fixed electrode
- 3 spring
- 4 substrate

Figure 1 – The schematic drawing of micro-electromechanical inertia shock switch

3.2

normally open micro-electromechanical shock inertial switch

micro-electromechanical inertial shock switch that is switched from open state to closed state under a certain acceleration, and recovered to open state after the acceleration disappears

3.3

closed state

contact of fixed and movable electrode

3.4

open state

separation of fixed and movable electrode

3.5

static threshold

constant acceleration at which the normally open inertial shock switch is closed

3.6

dynamic threshold

impact acceleration at which the normally open inertial shock switch is closed

3.7

contact resistance

resistance between fixed and movable electrode when inertial shock switch is closed

3.8

wireless gather system

system that gathers data by wireless communication technology

Essential ratings and characteristics

Recommended operating condition 4.1

The following items should be described in the specification, unless otherwise stated in the relevant procurement specifications.

a) temperature: -20 °C to 50 °C;

b) relative humidity: 20 %RH to 80 %RH;

c) atmospheric pressure: atmospheric pressure of test site.

4.2 **Characteristics**

Characteristics of the switch threshold are listed as shown in Table 1.

Table 1 - Characteristics of the switch threshold

Parameters		Symbol	Switch state	Test method
Static threshold	minimum	<i>a</i> ₁	≤ a ₁ , open	See 5.2
	maximum	a_2	$\geq a_2$, closed	See 5.2
Contact resistance		R	Meet the product requirements, closed	See 5.2
Dynamic threshold	minimum	<i>b</i> ₁	∠≤ b₁, open	See 5.3
	maximum	b_2	$\geq b_2$, closed	See 5.3

5 Test items and methods

5.1 Switch type

The resistance is measured by digital multimeter, which determines whether the switch is a normally open inertial switch.

5.2 Static threshold

5.2.1 Test method

5.2.1.1 Test system

Test system includes four parts: centrifuge, switch, open-closed test circuit and status indicator, as shown in Figure 2. The status indicator is the part of test system to indicate the closed state or open state of switch. For example, the lamp.

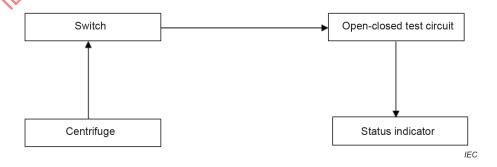


Figure 2 - Test system 1 of static threshold

5.2.1.2 Test procedure

- 1) Assemble open-closed test circuit and status indicator on centrifuge, and assemble switch on open-closed test circuit, ensuring centrifugal acceleration direction is the switch sensing direction.
- 2) Apply excitation voltage and reset open-closed test circuit, status indicator indicates the closed state.
- 3) According to static threshold design value of product, give centrifuge an acceleration which equals to the design value A_{11} .
 - a) If status indicator indicates the closed state, then decreasing A_{11} to A_{12} at a rate of product precision, and recording the indicator's state. Decreasing acceleration by degrees until status indicator indicates the open state, then the previous and current acceleration are the maximum static threshold and minimum static threshold respectively, as shown in Table 2, in which a_1 equals to A_{15} , and a_2 equals to A_{14} .
 - b) If status indicator indicates the open state, then increasing A_{11} to A_{21} at a rate of product precision, and recording the indicator's state. Increasing acceleration by degrees until status indicator indicates the closed state, then the previous and current acceleration are the minimum static threshold and maximum static threshold respectively, as shown in Table 2, in which a_1 equals to A_{41} , and a_2 equals to A_{51} .

Table 2 – Test parameters of static threshold

Case 1		Case 2	
Acceleration	State	Acceleration	State
A ₁₁	×	A ₁₁	V
A ₁₂	×	A_{21}	$\sqrt{}$
A ₁₃	×	A ₃₁	\checkmark
A ₁₄	×	A_{41}	\checkmark
A ₁₅	1 10	A ₅₁	×
Cey:	×O		
v. alaaad	\L \		

×: closed

√: open

5.2.2 Test method 2

5.2.2.1 Test system

Test system includes five parts: centrifuge, reference accelerometer, switch, open-closed test circuit and wireless gather system, as shown in Figure 3. The acceleration value is acquired through the output of reference accelerometer.

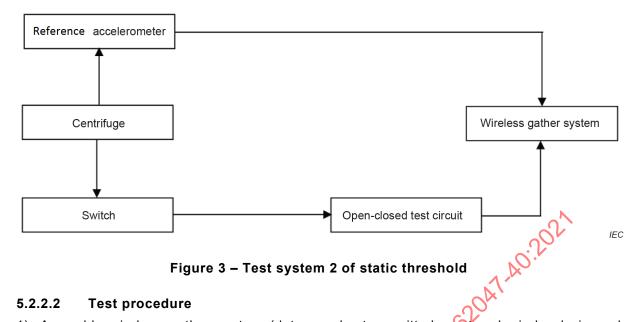


Figure 3 - Test system 2 of static threshold

5.2.2.2 Test procedure

- 1) Assemble wireless gather system (data can be transmitted or stored wirelessly in real time) and open-closed test circuit, as shown in Figure 4, on centrifuge, and assemble switch on open-closed test circuit. At the same time, assemble a reference accelerometer on centrifuge at the same radius location as switch, which makes the sensitive direction of switch and reference accelerometer is consistent with direction of centrifugal acceleration.
- 2) Apply excitation voltage, and give centrifuge an acceleration which equals to the design value according to static threshold design value of product. Sampling data in the test process according to technical requirement, and sampling output of reference accelerometer and voltage output of load resistance. Those output data points become two synchronous output curves in gather system, and acquiring jump point on voltage output of load resistance curve, as shown in Figure 5. If there is no jump point on curve, increasing acceleration given on centrifuge according to actual demand.
- 3) Starting from jump point in Figure 5, using Formula (1) to calculate contact resistance of switch corresponding to each sample point. When contact resistance of switch meets technical specifications, corresponding output of reference accelerometer is the static threshold. Comparing with test method 1 in 5.2.1, test method 2 can acquire more accurate static threshold.

$$R = R_L \left(\frac{U_S - U_{RL}}{U_{RL}} \right) \tag{1}$$

where,

is excitation voltage, in Volts; $U_{\mathcal{S}}$

is load resistance, in Ohms; R_L

R is contact resistance, in Ohms;

 U_{RL} is voltage of load resistance, in Volts.

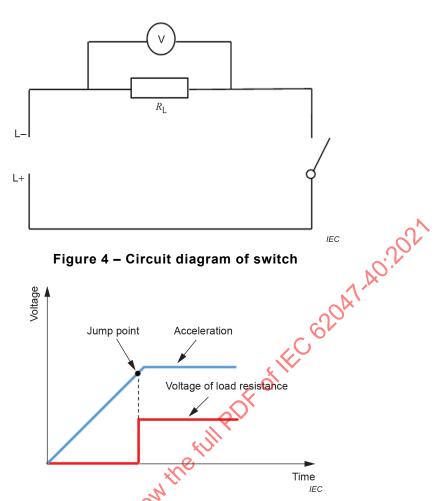


Figure 5 – Static threshold of switch

5.3 Dynamic threshold

5.3.1 Test system

Test system includes seven parts: shock test apparatus, reference accelerometer, switch, charge amplifier, open-closed test circuit, DC voltage regulator, and data acquisition system, as shown in Figure 6.

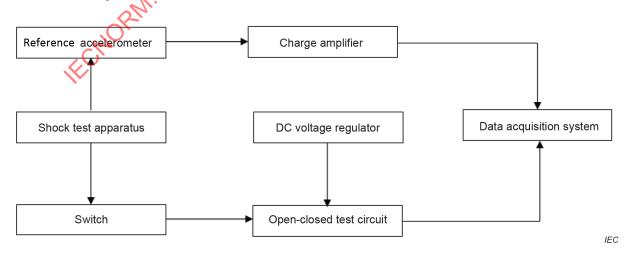


Figure 6 - Test system of dynamic threshold